MAZTxxxH Series

Silicon planar type

For surge absorption circuit

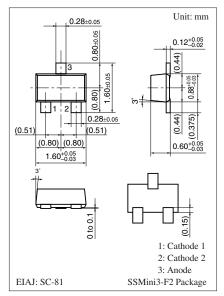
Features

- Two elements anode-common type
- Power dissipation P_D : 150 mW

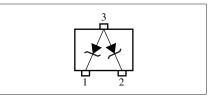
Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Power dissipation *	PD	150	mW	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	

Note) *: $P_D = 150 \text{ mW}$ achieved with a printed circuit board.



Internal Connection



Common Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions			Min	Тур	Max	Unit
Zener voltage*	Vz	IZ	Specified value					V
Zener rise operating resistance	R _{ZK}	IZ	Specified value	Refer to the list of the electrical characteristics within part numbers			Ω	
Zener operating resistance	R _Z	IZ	Specified value				Ω	
Reverse current	I _R	V _R	Specified value					μΑ

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. Electrostatic breakdown voltage: $\pm 10 \text{ kV}$

Test method: IEC1000-4-2 (C = 150 pF, R = 330 Ω , Contact discharge: 10 times)

3. *: The temperature must be controlled 25°C for V_{Z} mesurement.

 V_Z value measured at other temperature must be adjusted to $V_Z \left(25^\circ C\right)$

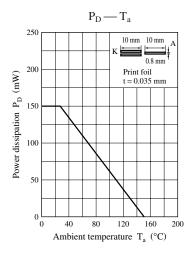
 V_Z guaranted 20 ms after current flow.

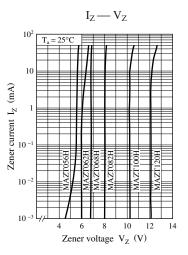
Panasonic

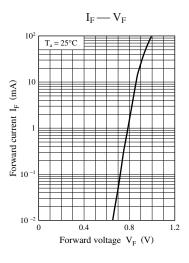
Electrical characteristics within part numbers $T_a = 25^{\circ}C \pm 3^{\circ}C$

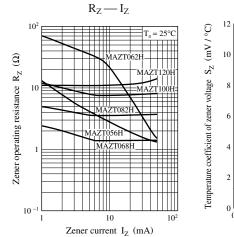
Part number	Zener voltage V _Z (V)		Reverse current I _R (mA)		$\begin{array}{c} \text{Zener} \\ \text{operating} \\ \text{resistance} \\ \text{R}_{\text{Z}}\left(\Omega\right) \end{array}$	Zener rise operating resistance $R_{ZK}(\Omega)$	Marking symbol		
	Min	Nom	Max	I _Z (mA)	Max	V _R (V)	I _z = 5 mA Max	l _z = 0.5 mA Max	
MAZT056H	5.3	5.6	6.0	5	0.5	2.5	50	300 *	5.6Z
MAZT062H	5.8	6.2	6.6	5	0.2	4	50	100	6.2Z
MAZT068H	6.4	6.8	7.2	5	0.1	4	30	60	6.8Z
MAZT082H	7.7	8.2	8.7	5	0.1	5	30	60	8.2Z
MAZT100H	9.4	10.0	10.6	5	0.05	7	30	60	10Z
MAZT120H	11.4	12.0	12.7	5	0.05	9	30	80	12Z

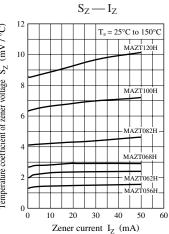
Note) *: $I_Z = 1.0 \text{ mA}$

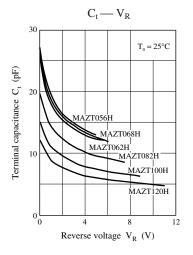












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